Supporting Information

In-Situ, Seed-Free Formation of Ruddlesden–Popper Perovskite Cs₂PbI₂Cl₂ Nanowires/PbI₂ Heterojunction for High-Responsivity, Self-Powered Photodetector

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Figure S1. Surficial SEM image of FTO/TiO₂ substrate.



Figure S2. XPS survey spectra of PbI₂ film and Cs₂PbI₂Cl₂ nanowires/PbI₂ heterojunction obtained with 6 mg/mL CsCl/MeOH.



Figure S3. EDS mapping image of a Cs₂PbI₂Cl₂ nanowire.



Figure S4. Linear-scale dark J-V curves of self-powered PDs fabricated with pristine PbI₂ film and Cs₂PbI₂Cl₂ nanowires/PbI₂ heterojunctions formed with 4, 6, and 8 mg/mL CsCl/MeOH.



Figure S5. Equivalent circuit model for fitting the EIS Nyquist curves of self-powered PDs fabricated with pristine PbI₂ film and Cs₂PbI₂Cl₂ nanowires/PbI₂ heterojunction produced with 6 mg/mL CsCl/MeOH.